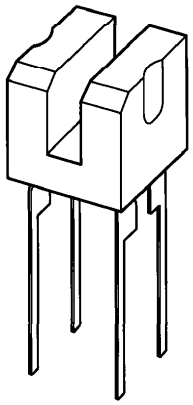
TOSHIBA PHOTO-INTERRUPTER INFRARED LED + PHOTOTRANSISTOR

TLP812

MOTOR ROTATION AND IRIS DETECTION FOR CAMERAS

TRACK DETECTION IN MICRO FLOPPY DISK DRIVE

- Very small package
- High resolution : Slit width = 0.4 mm
- Gap : 1 mm
- Can be mounted directly on PCB using the stand off of lead.



TOSHIBA 11-4D1

Weight : 0.08 g (typ.)

MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT
LED	Forward Current	I_F	50	mA
	Forward Current Derating (Ta > 25°C)	I_F / °C	−0.67	mA / °C
	Reverse Voltage	V_R	5	V
DETECTOR	Collector-Emitter Voltage	V_{CEO}	35	V
	Emitter Collector Voltage	V_{ECO}	5	V
	Collector Current	I_C	20	mA
	Collector Power Dissipation	P_C	75	mW
	Collector Power Dissipation Derating (Ta > 25°C)	ΔP_C / °C	−1	mW / °C
Operating Temperature Range		T_{opr}	−25~85	°C
Storage Temperature Range		T_{stg}	−40~100	°C

OPTICAL AND ELECTRICAL CHARACTERISTICS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	Min	Typ.	Max	UNIT
LED	Forward Voltage	V_F	I_F = 10 mA	1.00	1.15	1.30	V
	Reverse Current	I_R	V_R = 5 V	—	—	10	μA
	Capacitance	C_T	V = 0, f = 1 MHz	—	30	—	pF
DETECTOR	Dark Current	I_D (I_{CEO})	V_{CE} = 20 V, I_F = 0	—	—	100	nA
	Capacitance	C_T	V = 0, f = 1 MHz	—	13	—	pF
COUPLED	Current Transfer Ratio	I_C / I_F	V_{CE} = 0.6 V, I_F = 5 mA	5	—	—	%
	Collector-Emitter Saturation Voltage	$V_{CE\ (sat)}$	I_F = 8 mA, I_C = 0.1 mA	—	0.1	0.4	V
	Rise Time	t_r	V_{CC} = 5 V, I_C = 2 mA, R_L = 1 kΩ	—	50	—	μs
	Fall Time	t_f		—	50	—	

PRECAUTIONS

The following points must be borne in mind.

1. Soldering temperature : 260°C max
   Soldering time : 5 s max
   (Soldering must be performed 1.5 mm under the package body.)
2. Ensure that no residual flux or chemicals adhere to the light-emitting and light-receiving surfaces.

ENVIRONMENT

○ The device should not be exposed to corrosive gases, such as hydrogen sulfide gas and a sea breeze.

○ The device should not be exposed to dust.

○ The device should not be exposed to direct sunlight.
In essence, the device should not be subjected to any load which may result in deformation or performance deterioration.

CIRCUIT DESIGN

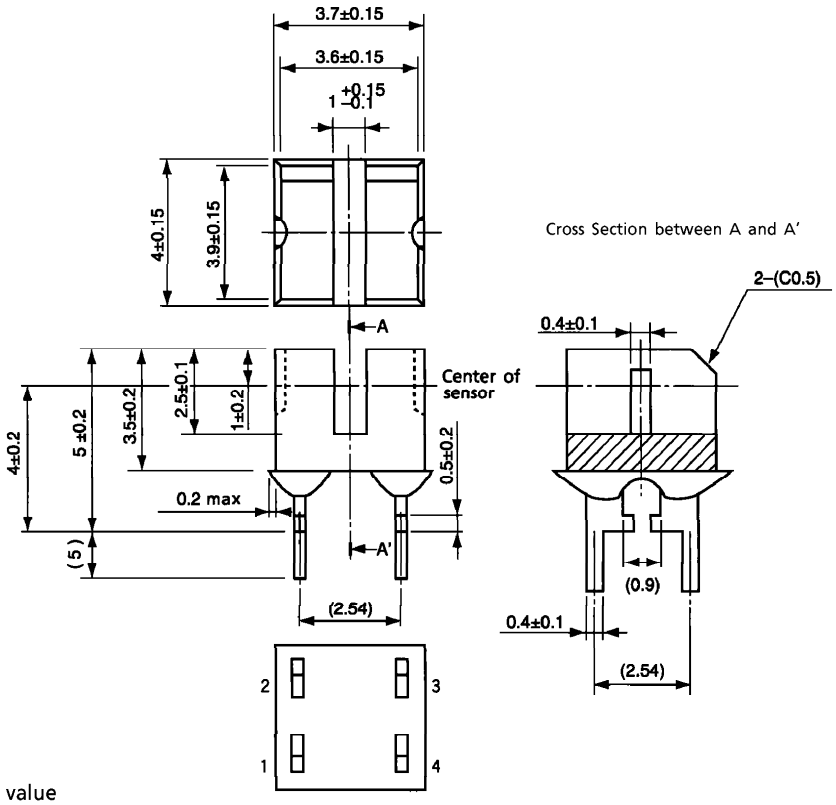
- Conversion efficiency falls over time due to the current which flows in the infrared LED.
  When designing a circuit, take into account this change in conversion efficiency over time.
  The ratio of fluctuation in conversion efficiency to fluctuation in infrared LED optical output is 1 : 1.

$$\frac{I_C / I_F\,(t)}{I_C / I_F\,(0)} = \frac{P_O\,(t)}{P_O\,(0)}$$

PACKAGE DIMENSIONS

11-4D1

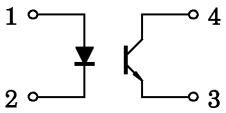
Unit : mm



( ) : Reference value

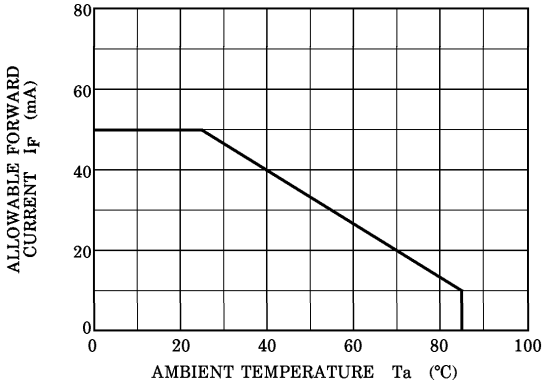
Weight : 0.08 g (typ.)

PIN CONNECTION

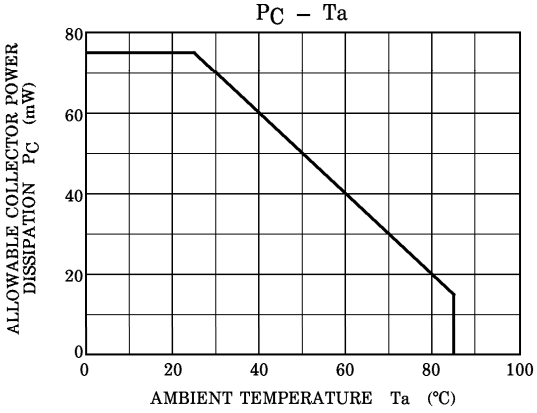


1. Cathode
2. Anode
3. Emitter
4. Collector

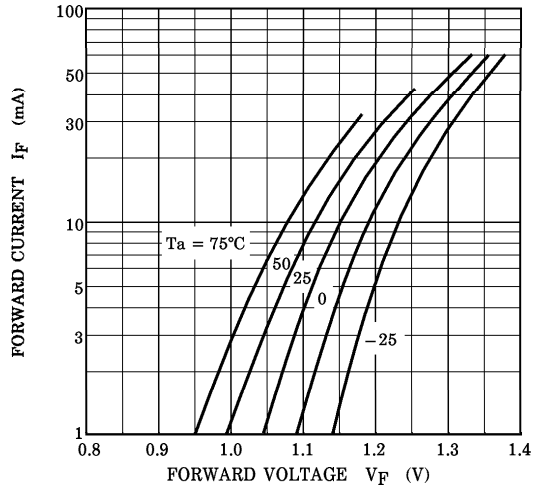
I_F – Ta



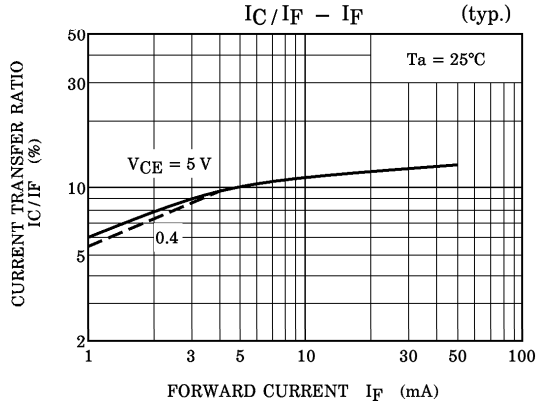
P_C – Ta



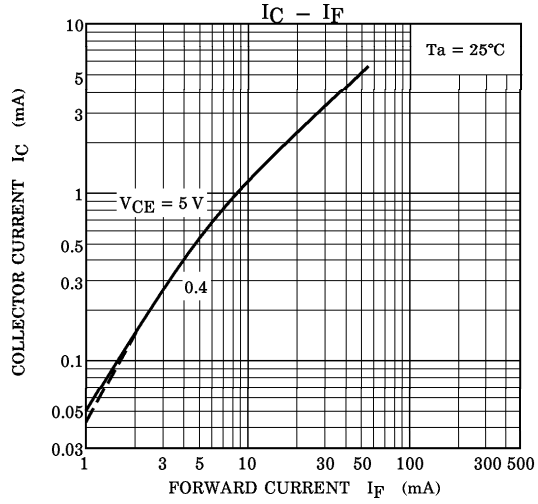
I_F – V_F (typ.)



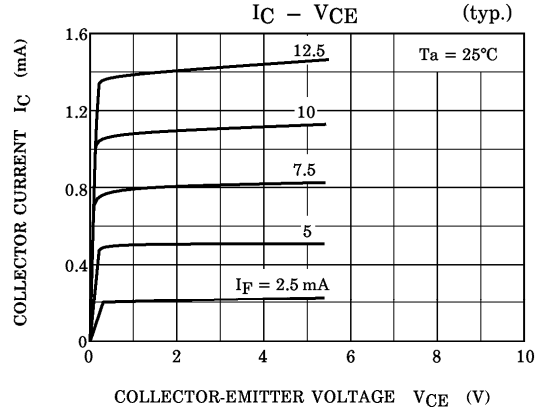
I_C / I_F – I_F (typ.)



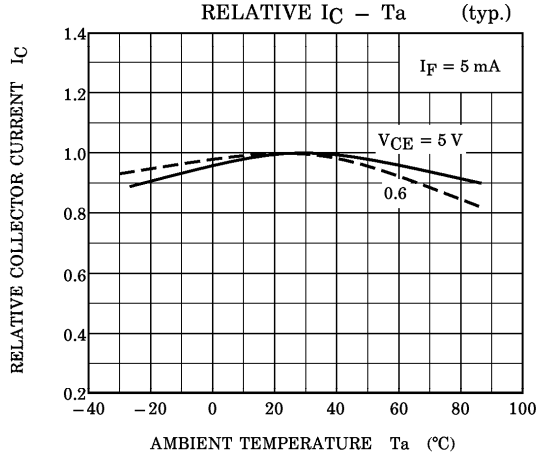
I_C – I_F



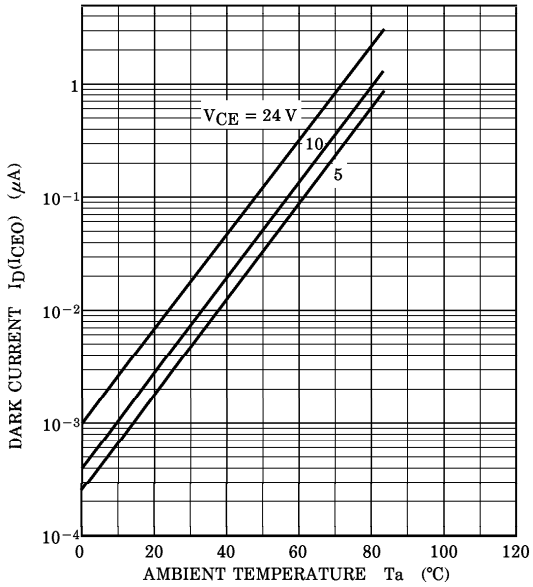
I_C – V_{CE} (typ.)



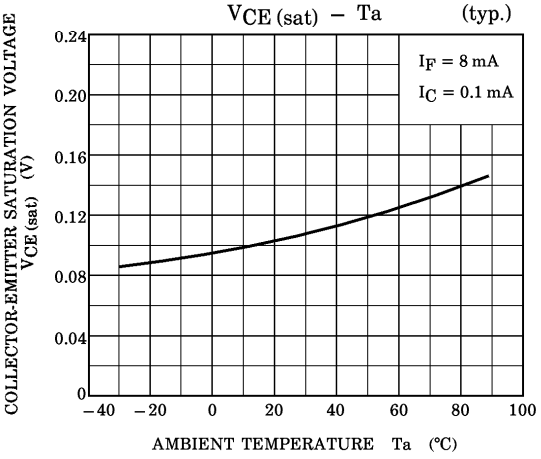
RELATIVE I_C – Ta (typ.)



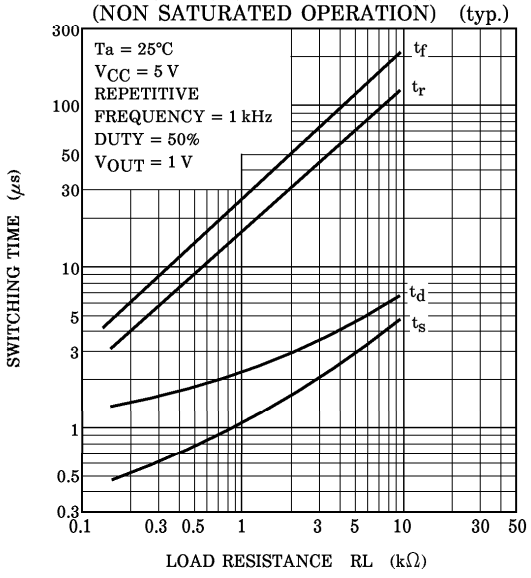
I_D (I_{CEO}) – Ta (typ.)



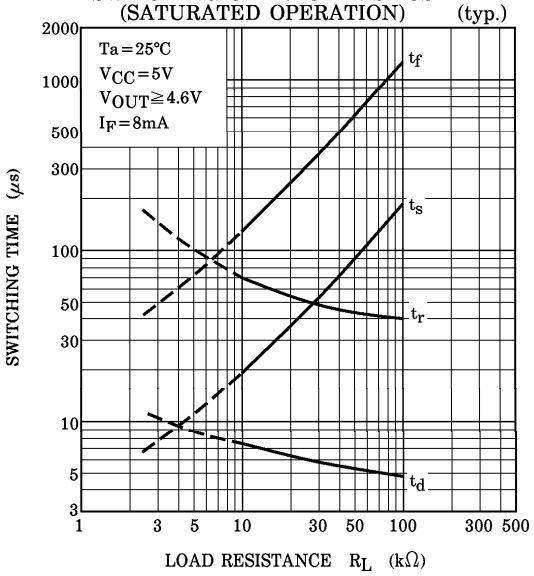
V_{CE} (sat) – Ta (typ.)



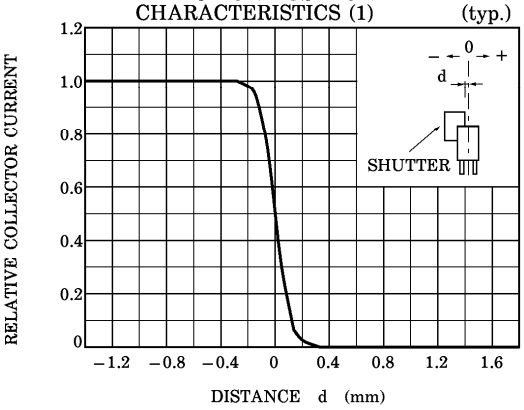
SWITCHING CHARACTERISTICS (NON SATURATED OPERATION) (typ.)



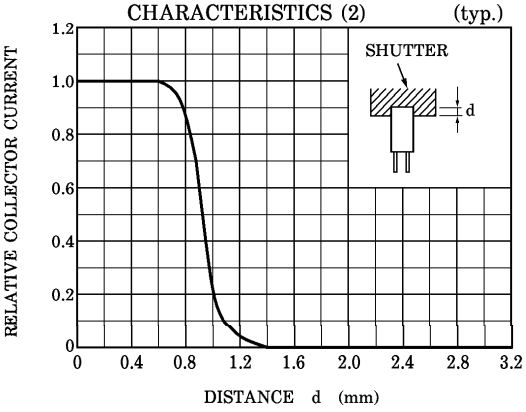
SWITCHING CHARACTERISTICS
(SATURATED OPERATION) (typ.)



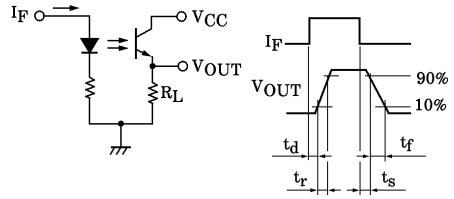
DETECTION POSITION
CHARACTERISTICS (1) (typ.)



DETECTION POSITION
CHARACTERISTICS (2) (typ.)



SWITCHING TIME TEST CIRCUIT



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